

HMC519LC4

04 1017

GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

Typical Applications

The HMC519LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military & Space

Features

Noise Figure: 3.5 dB

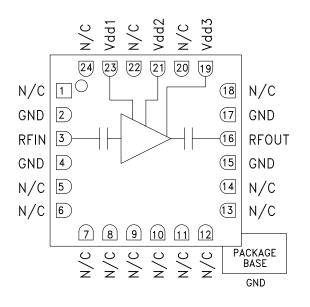
Gain: 14 dB

Output IP3: +23 dBm

Single Supply: +3V @ 75 mA 50 Ohm Matched Input/Output

24 Lead Ceramic 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC519LC4 is a high dynamic range GaAs pHEMT MMIC Low Noise Amplifier (LNA) housed in a leadless 4 x 4 mm ceramic surface mount package. The amplifier operates between 18 and 31 GHz, providing 14 dB of small signal gain, 3.5 dB noise figure and output IP3 of +23 dBm, while requiring only 75 mA from a +3V single supply. The P1dB output power of +11 dBm, enables the LNA to function as a LO driver for balanced, I/Q or image reject mixers. The HMC519LC4 also features I/Os that are DC blocked and internally matched to 50 Ohms, making it ideal for microwave radio and VSAT applications.

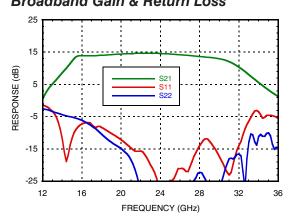
Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vdd 1, 2, 3 = +3V

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		18 - 28		28 - 31			GHz
Gain	11.4	14.4		10.2	13.2		dB
Gain Variation Over Temperature		0.016	0.026		0.016	0.026	dB/ °C
Noise Figure		3.5	5.5		3	5	dB
Input Return Loss		15			17		dB
Output Return Loss		20			22		dB
Output Power for 1 dB Compression (P1dB)	8	11		9.2	12.2		dBm
Saturated Output Power (Psat)		14			15.4		dBm
Output Third Order Intercept (IP3)		23			24		dBm
Supply Current (Idd)		75	95		75	95	mA

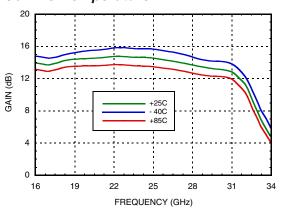


GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

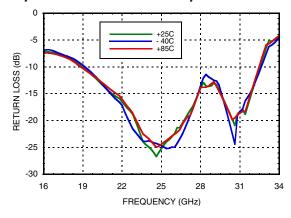
Broadband Gain & Return Loss



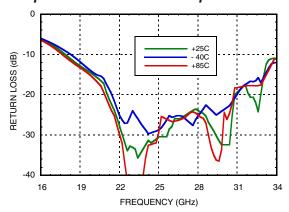
Gain vs. Temperature



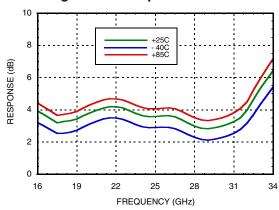
Input Return Loss vs. Temperature



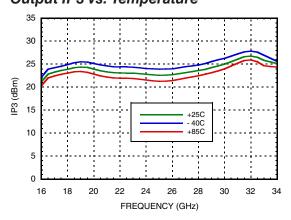
Output Return Loss vs. Temperature



Noise Figure vs. Temperature



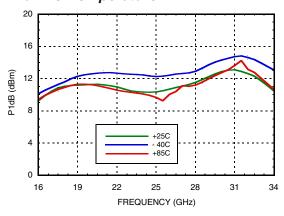
Output IP3 vs. Temperature



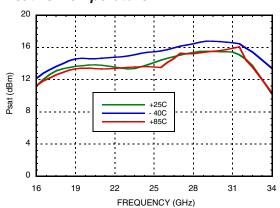


GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

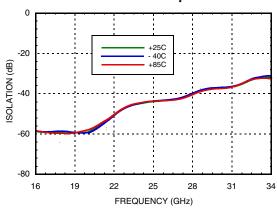
P1dB vs. Temperature



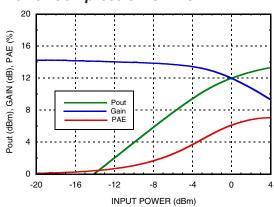
Psat vs. Temperature



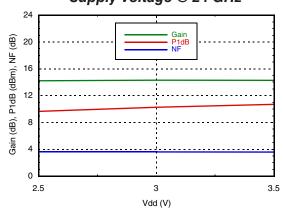
Reverse Isolation vs. Temperature



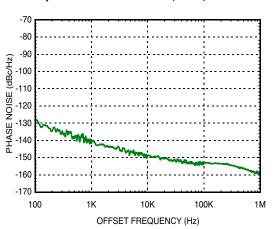
Power Compression @ 24 GHz



Gain, Noise Figure & Power vs. Supply Voltage @ 24 GHz



Additive Phase Noise Vs Offset Frequency, RF Frequency = 26.5 GHz, RF Input Power = 5 dBm (Psat)





/04.1017

GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2, Vdd3)	+3.5 Vdc
RF Input Power (RFIN)(Vdd = +3.0 Vdc)	+20 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 13 mW/°C above 85 °C)	1.2 W
Thermal Resistance (channel to package bottom)	76.9 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to 85 °C
ESD Sensitivity (HBM)	Class 1B

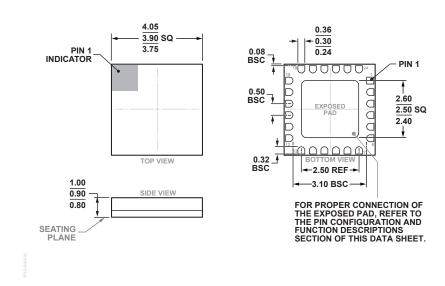
Typical Supply Current vs. Vdd

Vdd (V)	Idd (mA)
2.5	72
3.0	75
3.5	78

Note: Amplifier will operate over full voltage ranges shown above.



Outline Drawing



24-Terminal Ceramic Leadless Chip Carrier [LCC] (E-24-1)
Dimensions shown in millimeters.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC519LC4	Alumina, White	Gold over Nickel	MSL3 ^[1]	H519 XXXX

^[1] Max peak reflow temperature of 260 $^{\circ}\text{C}$

^{[2] 4-}Digit lot number XXXX



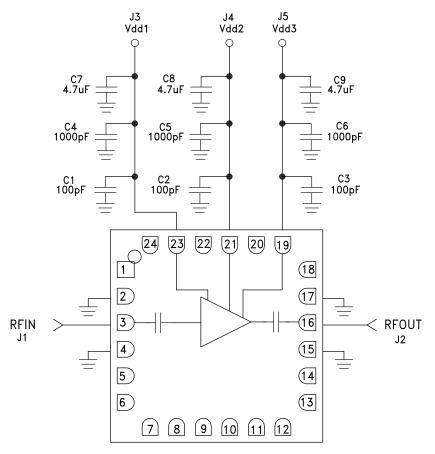
/04.1017

GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1, 5 - 14, 18, 20, 22, 24	N/C	Not Connected	
2, 4, 15, 17	GND	Package bottom has exposed metal paddle that must be connected to RF/DC ground.	GND =
3	RFIN	This pad is AC coupled and matched to 50 Ohms	RFIN ○──
16	RFOUT	This pad is AC coupled and matched to 50 Ohms	— —○ RFOUT
19, 21, 23	Vdd3, Vdd2, Vdd1	Power Supply Voltage for the amplifier. See application circuit for required external components.	oVdd1,2,3

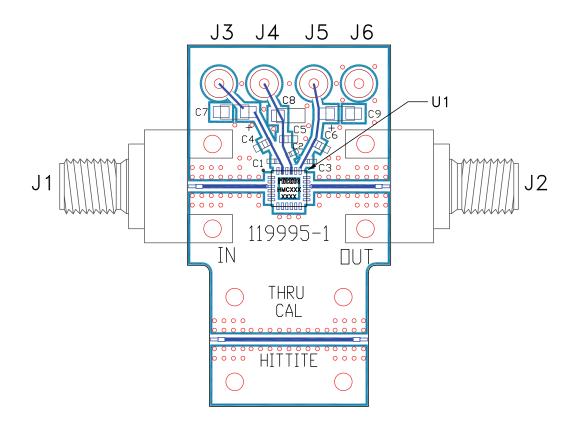
Application Circuit





GAAS PHEMT MMIC LOW NOISE AMPLIFIER, 18 - 31 GHz

Evaluation PCB



List of Material for Evaluation PCB 119667 [1]

Item	Description
J1, J2	2.92mm PCB mount K-Connector
J3 - J6	DC Pin
C1, C2, C3	100pF Capacitor, 0402 Pkg.
C4, C5, C6	1000pF Capacitor, 0603 Pkg.
C7, C8, C9	4.7 μF Capacitor, Tantalum
U1	HMC519LC4 Amplifier
PCB [2]	11995 Evaluation PCB

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, upon request.

^[2] Circuit Board Material: Rogers 4350.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.:

HMC519LC4 119667-HMC519LC4 HMC519LC4TR